NSN 5961-01-096-6323

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View Online at https://aerobasegroup.com/nsn/5961-01-096-6323 **Inclosure Material:** Metal **Overall Length:** Between 0.970 inches and 1.218 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.424 inches and 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 120.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 10.00 amperes zero-gate-voltage source current blank **Power Rating Per Characteristic:** 30.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 13973-862162 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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